

100V 52A N-Channel Enhancement Mode Power MOSFET

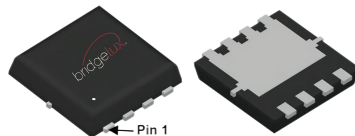
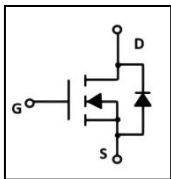
Features

- $R_{DS(on)} \leq 13m\Omega$ @ $V_{gs}=10V$
- Advanced SGT process
- Excellent $R_{DS(on)}$ and Low Gate Charge
- Lead free product is acquired

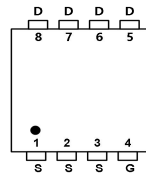
Application

- High Frequency Switching
- Synchronous Rectification

SYMBOL



PDFN5*6



ASSEMBLY MESSAGE

Product Name	Package	Packaging
BXS130N10C	PDFN5*6	Reel

ABSOLUTE MAXIMUM RATINGS ($T_C=25^\circ C$ unless otherwise noted)

Parameter		Symbol	Rating	Unit
			PDFN5*6	
Drain-Source Voltage		V_{DSS}	100	V
Drain Current	Continuous ($T_C = 25^\circ C$)	I_D	52	A
	Continuous ($T_C = 100^\circ C$)		33	A
Drain Current	Pulsed (Note1)	I_{DM}	208	A
Single Pulsed Avalanche Energy		EAS	48	mJ
Gate-Source Voltage		V_{GSS}	± 20	V
Power Dissipation	$T_C = 25^\circ C$	P_D	57	W
Maximum Junction Temperature		T_J	150	$^\circ C$
Storage Temperature Range		T_{STG}	-55 to 150	$^\circ C$

Note: 1. Repetitive Rating: Pulse width limited by maximum junction temperature

THERMAL CHARACTERISTICS

Parameter	Symbol	Max.	Unit
		PDFN5*6	
Thermal Resistance, Junction to Case	$R_{\theta JC}$	2.2	$^\circ C / W$

ELECTRICAL CHARACTERISTICS ($T_J=25^{\circ}\text{C}$, unless otherwise Noted)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V, I_D=250\mu A$	100			V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=80V, V_{GS}=0V$			1	μA
Gate-Body Leakage Current, Forward	I_{GSS}	$V_{GS}=20V$			100	nA
Gate-Body Leakage Current, Reverse		$V_{GS}=-20V$			-100	nA
ON CHARACTERISTICS						
Gate Threshold Voltage	$V_{GS(TH)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	1.2	1.8	2.6	V
Drain-Source On-State Resistance	$R_{DS(ON)}$	$V_{GS}=10V, I_D=20A$		10.5	13	$m\Omega$
		$V_{GS}=4.5V, I_D=10A$		14.5	17	$m\Omega$
DYNAMIC PARAMETERS						
Input Capacitance	C_{ISS}	$V_{DS}=50V, V_{GS}=0V,$ $f=1.0MHz$		1782		μF
Output Capacitance	C_{OSS}			251		μF
Reverse Transfer Capacitance	C_{RSS}			23		μF
SWITCHING PARAMETERS						
Turn-ON Delay Time	$t_{D(ON)}$	$V_{DD}=50V, I_D=20A, V_{GS}$ $= 10V, R_G=3\Omega$		35		ns
Turn-ON Rise Time	t_R			19		ns
Turn-OFF Delay Time	$t_{D(OFF)}$			33		ns
Turn-OFF Fall-Time	t_F			11		ns
Total Gate Charge(Note2)	Q_G	$V_{DS}=50V, V_{GS}=10V,$ $I_D=20A$		35		nC
Gate Source Charge	Q_{GS}			8		nC
Gate Drain Charge	Q_{GD}			9.5		nC
SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS						
Drain-Source Diode Forward Voltage	V_{SD}	$I_S=20A, V_{GS}=0V$			1.4	V
Diode Continuous Forward Current	I_S				52	A
Maximum Pulsed Drain to Source Diode Forward Current	I_{SM}				208	A
Reverse Recovery Time	t_{rr}	$I_F=20A,$ $di/dt=100A/\mu s$		42		ns
Reverse Recovery Charge	Q_{rr}			52		nC

Note: 2. Essentially independent of operating temperature

TYPICAL CHARACTERISTICS

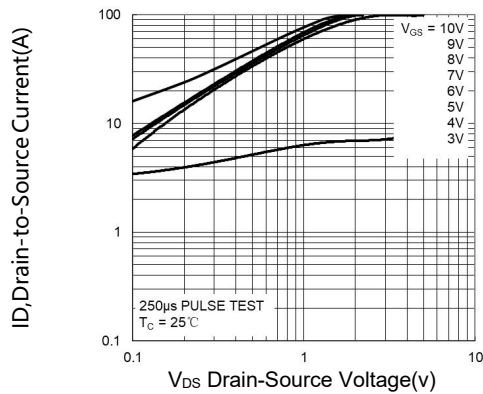


Figure1. Typical Output Characteristics

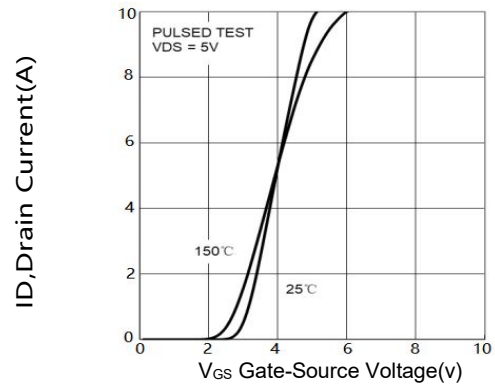


Figure2. Typical Transfer Characteristics

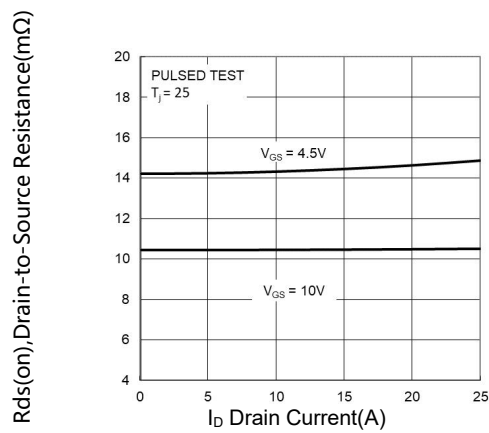


Figure3. On-Resistance versus Drain Current

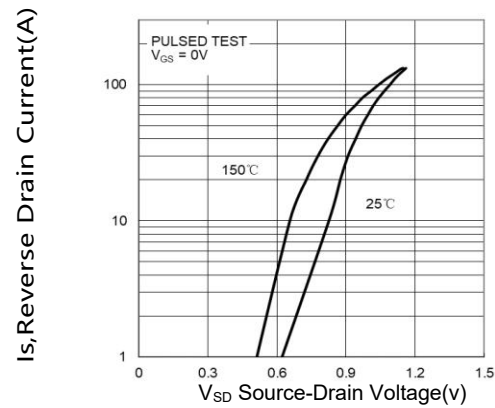


Figure4. Diode forward voltage versus Current

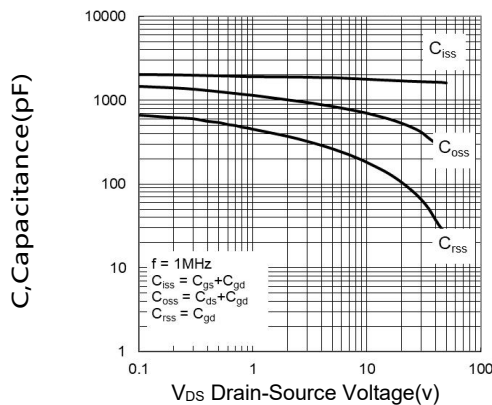


Figure5. Typical Capacitance versus V_{DS}

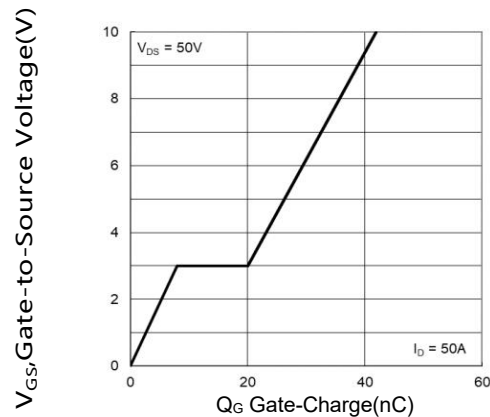


Figure6. Typical Gate Charge versus V_{GS}

TYPICAL CHARACTERISTICS(Cont.)

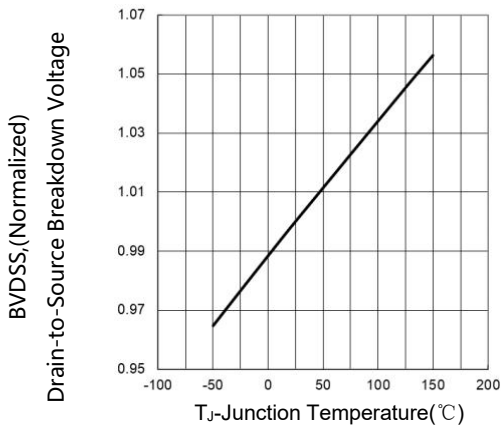


Figure7. BV_{DSS} Variation with Temperature

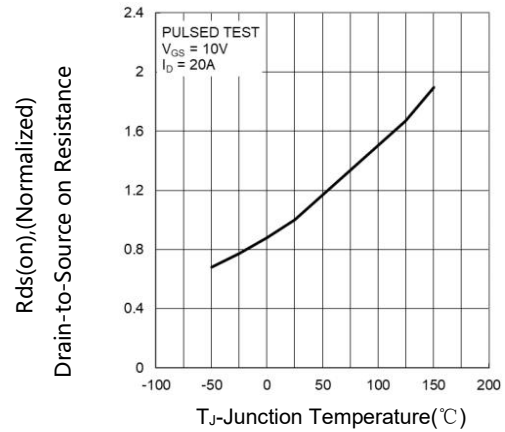


Figure8. On-Resistance Variation with Temperature

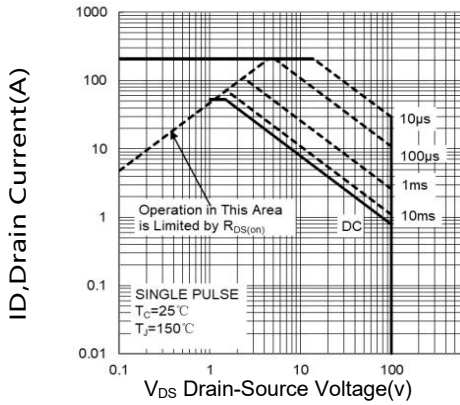


Figure9. Maximum Safe Operating Area

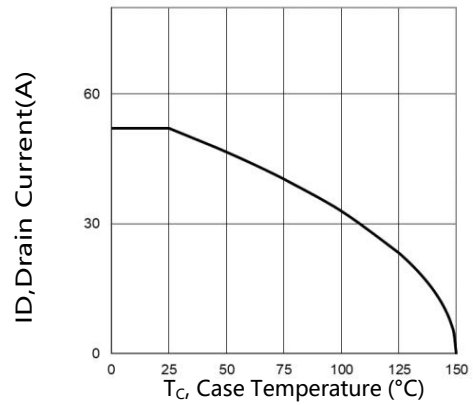
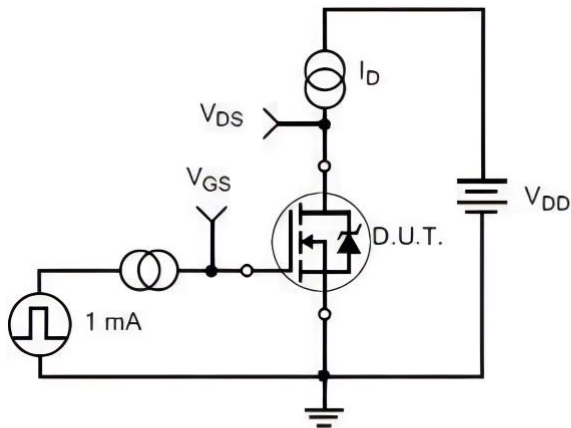
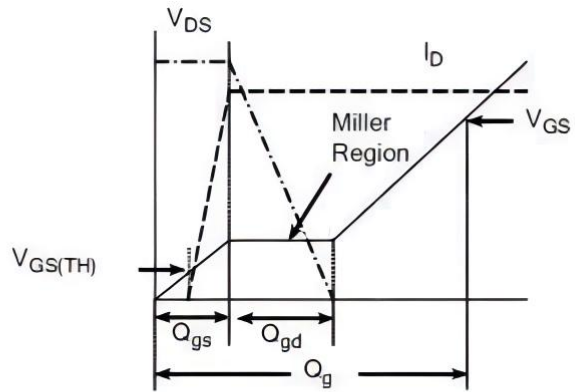


Figure10. Maximum Continuous Drain Current versus Case Temperature

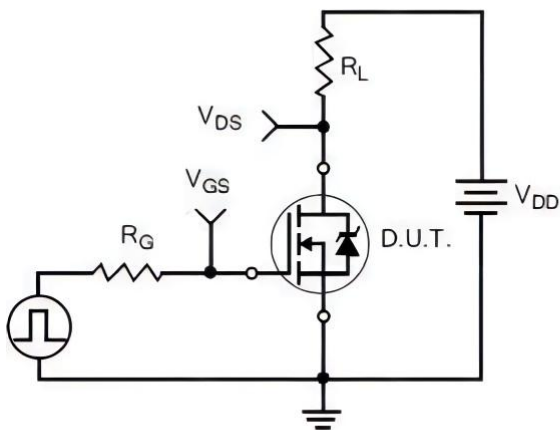
TEST CIRCUITS AND WAVEFORMS



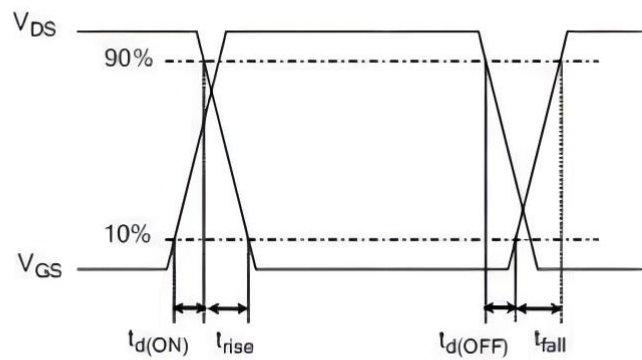
Gate Charge Test Circuit



Gate Charge Waveform

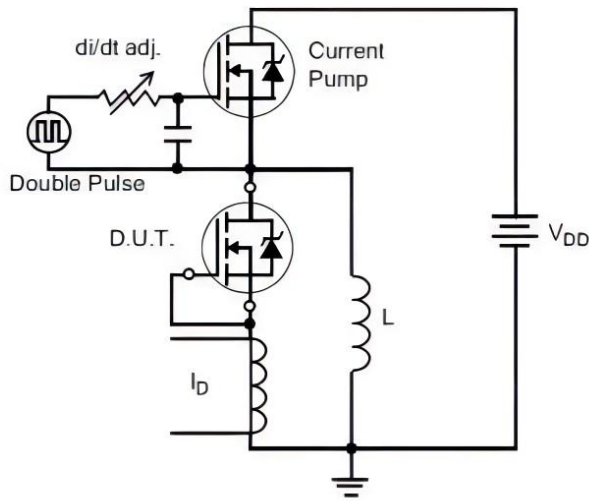


Resistive Switching Test Circuit

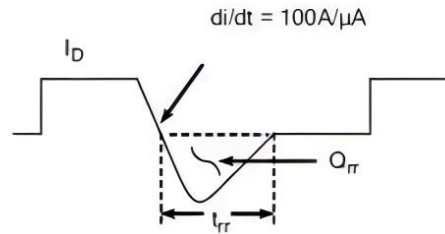


Resistive Switching Waveforms

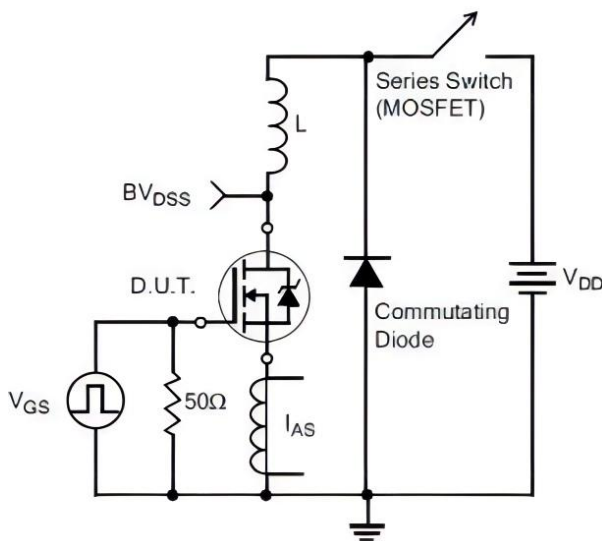
TEST CIRCUITS AND WAVEFORMS(Cont.)



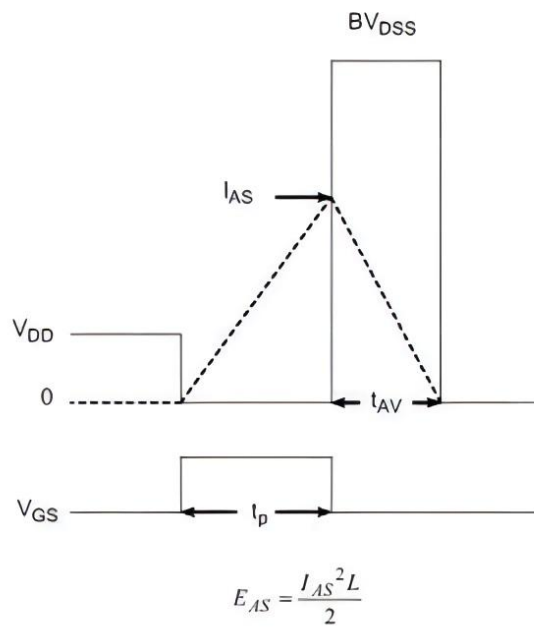
Diode Reverse Recovery Test Circuit



Diode Reverse Recovery Waveform

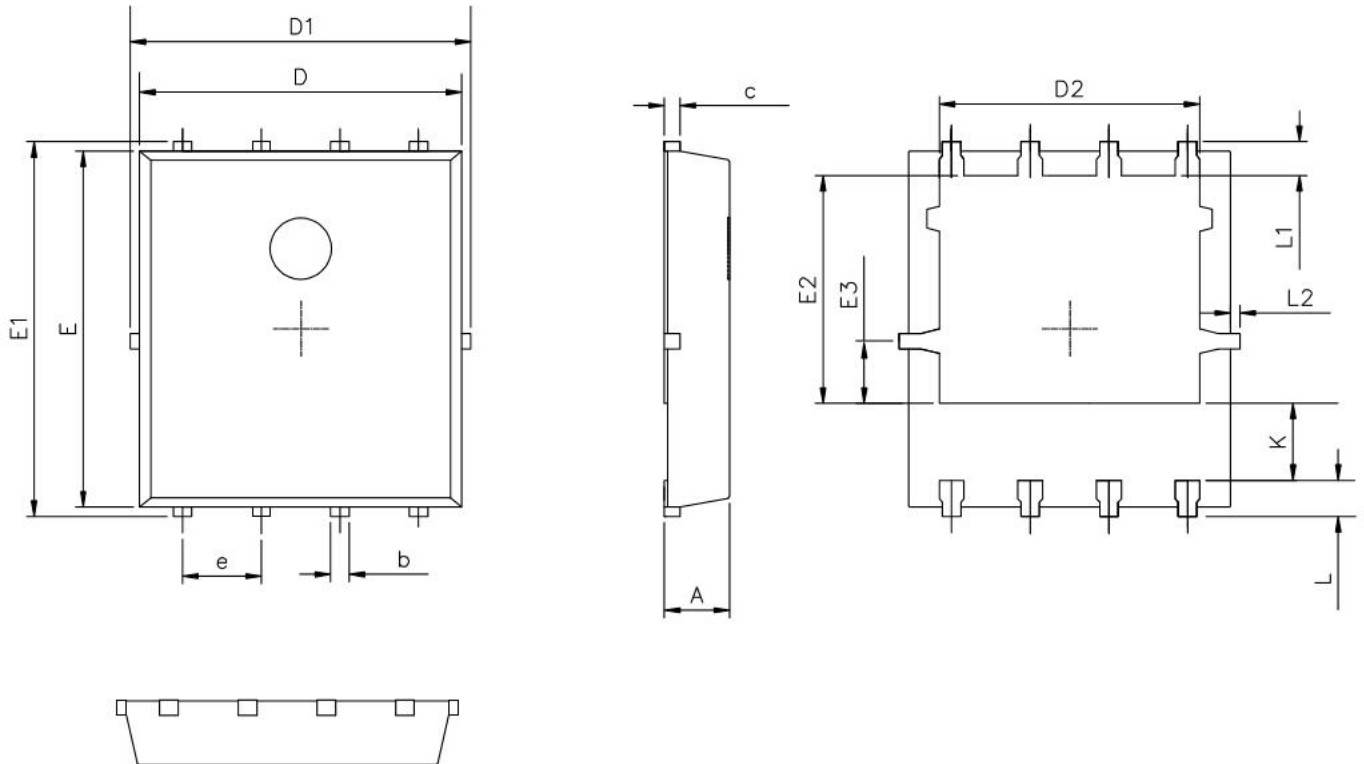


Unclamped Inductive Switching Test Circuit

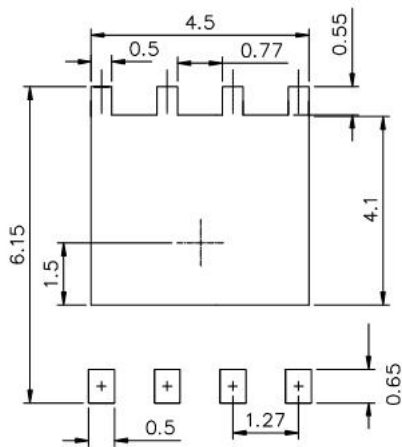


Unclamped Inductive Switching Waveforms

PDFN5*6 Package



RECOMMENDED LAND PATTERN



Symbol	Dimensions In Millimeters		
	min.	nom.	max.
A	0.9	1	1.1
b	0.25	0.35	0.5
c	0.1	0.2	0.3
D	0.48	5	5.3
D1	0.49	5.1	5.5
D2	3.92	4.02	4.2
E	5.65	5.75	5.85
E1	5.9	6.05	6.2
E2	3.32	3.52	3.78
E3	0.8	0.9	1
e		1.27	
L	0.4	0.55	0.7
L1		0.65	
L2	0		0.15
K	1	1.3	1.5

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